



## **Dual P-Channel 20-V (D-S) MOSFET**

PRODUCT SUMMARY									
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)						
- 20	0.116 at V <sub>GS</sub> = - 4.5 V	- 4.5 <sup>a</sup>							
	0.155 at V <sub>GS</sub> = - 2.5 V	- 4.5 <sup>a</sup>	4.9 nC						
	0.205 at V <sub>GS</sub> = - 1.8 V	- 4.5 <sup>a</sup>							

#### **FEATURES**

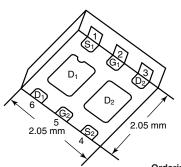
- · Halogen-free
- TrenchFET® Power MOSFET
- New Thermally Enhanced PowerPAK® SC-70 Package
  - Small Footprint Area
  - Low On-Resistance

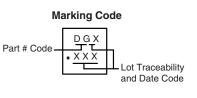
**APPLICATIONS** 

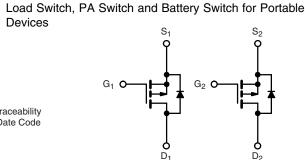
**Devices** 



#### PowerPAK SC-70-6 Dual







Ordering Information: SiA911ADJ-T1-GE3 (Lead (Pb)-free and Halogen-free) P-Channel MOSFET P-Channel MOSFET

Parameter		Symbol	Limit	Unit		
Drain-Source Voltage		$V_{DS}$	- 20	V		
Gate-Source Voltage		$V_{GS}$	± 8			
	T <sub>C</sub> = 25 °C		- 4.5 <sup>a</sup>			
Continuous Drain Current (T <sub>J</sub> = 150 °C)	$T_C = 70 ^{\circ}\text{C}$ $T_A = 25 ^{\circ}\text{C}$	I <sub>D</sub>	- 4.5 <sup>a</sup> - 3.2 <sup>b, c</sup>	$\dashv$		
	T <sub>A</sub> = 70 °C		- 2.6 <sup>b, c</sup>	Α		
Pulsed Drain Current	·	I <sub>DM</sub>	- 8			
Continuous Source-Drain Diode Current	$T_C = 25 ^{\circ}C$ $T_A = 25 ^{\circ}C$	I <sub>S</sub>	- 4.5 <sup>a</sup> - 1.5 <sup>b, c</sup>			
	T <sub>C</sub> = 25 °C		6.5			
Maximum Power Dissipation	$T_C = 70 ^{\circ}\text{C}$ $T_A = 25 ^{\circ}\text{C}$	P <sub>D</sub>	4.2 1.8 <sup>b, c</sup>	_ w		
	T <sub>A</sub> = 70 °C		1.1 <sup>b, c</sup>			
Operating Junction and Storage Temperature Ra	ange	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C		
Soldering Recommendations (Peak Temperature	e) <sup>d, e</sup>		260			

THERMAL RESISTANCE RATINGS									
Parameter		Symbol	Typical	Maximum	Unit				
Maximum Junction-to-Ambient <sup>b, f</sup>	t ≤ 5 s	R <sub>thJA</sub>	55	70	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	15	19	O/ <b>VV</b>				

#### Notes:

- a. Package limited.
- b. Surface Mounted on 1" x 1" FR4 board.
- c. t = 5 s.
- d. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.
- f. Maximum under Steady State conditions is 110 °C/W.



Static						
				•	L	l
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 20			V
V <sub>DS</sub> Temperature Coefficient	ΔV <sub>DS</sub> /T <sub>J</sub>	J 050 A		- 19		mV/°C
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I <sub>D</sub> = - 250 μA		2.4		
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.4		- 1	V
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA
		V <sub>DS</sub> = - 20 V, V <sub>GS</sub> = 0 V			- 1	μΑ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 20 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			- 10	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le 5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 8			Α
	(* )	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 2.8 A		0.096	0.116	Ω
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 2.3 A		0.126	0.155	
	20(0)	V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 0.54 A		0.165	0.205	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 2.8 A		7		S
Dynamic <sup>b</sup>	0.0					
Input Capacitance	C <sub>iss</sub>			345	1	1
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> = - 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		65		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	VDS - 10 V, VGS - 0 V, I - I III IZ		50		
Tieverse fransier Capacitance	rss	V <sub>DS</sub> = - 10 V, V <sub>GS</sub> = - 8 V, I <sub>D</sub> = - 3.5 A		8.4	13	<del>                                     </del>
Total Gate Charge	Qg	VDS = 10 V, VGS = 0 V, ID = 0.3 A		4.9	7.4	
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> = - 10 V, V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 3.5 A		0.75	7.4	nC
Gate-Drain Charge	Q <sub>gd</sub>	VDS = 10 V, VGS = 1 V, ID = 0 //		1.2		
Gate Resistance	R <sub>g</sub>	f = 1 MHz		6		Ω
Turn-On Delay Time	t <sub>d(on)</sub>	1 - 1 1/11/12		15	25	32
Rise Time	t <sub>r</sub>	$V_{DD} = -10 \text{ V, R}_{1} = 2.85 \Omega$		45	70	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \simeq -3.5 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_q = 1 \Omega$		20	30	-
Fall Time	t <sub>f</sub>	D = 0.0 1.9 1 GEN 1.0 1, 1.9		10	15	
Turn-On Delay Time				5	10	ns
Rise Time	t <sub>d(on)</sub>	V - 10 V B - 2.95 O		10	15	
	t <sub>r</sub>	$V_{DD} = -10 \text{ V}, R_L = 2.85 \Omega$ $I_D \cong -3.5 \text{ A}, V_{GEN} = -8 \text{ V}, R_g = 1 \Omega$				
Turn-Off Delay Time	t <sub>d(off)</sub>	1D = 0.071, VGEN = 0 V, 11g = 132		20	30	
Fall Time  Drain-Source Body Diode Characterist	t <sub>f</sub>			10	15	
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>C</sub> = 25 °C			- 4.5	
Pulse Diode Forward Current	I <sub>SM</sub>	10-20-0			- 4.5	Α
Body Diode Voltage	V <sub>SD</sub>	I <sub>S</sub> = - 1.0 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V
Body Diode Reverse Recovery Time		is 1.0 A, VGS - 0 V			60	-
Body Diode Reverse Recovery Time  Body Diode Reverse Recovery Charge	t <sub>rr</sub>			30		ns
	$Q_{rr}$	$I_F = -4.5 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		20	40	nC
Reverse Recovery Fall Time	t <sub>a</sub>	1F = -4.5  A,  ul/ul = 100  A/µs,  IJ = 25  C		15		

#### Notes:

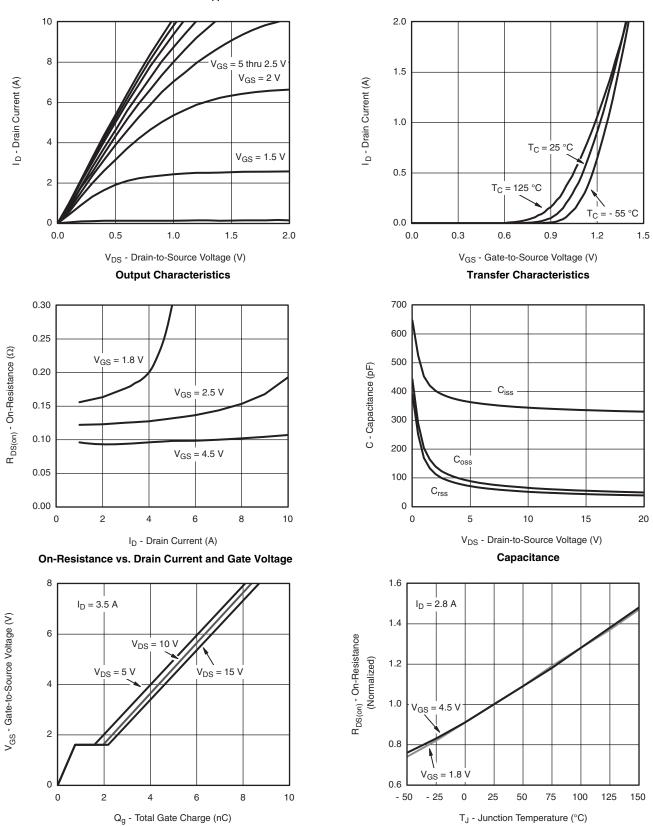
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$ 

b. Guaranteed by design, not subject to production testing.



## **TYPICAL CHARACTERISTICS** $T_A = 25$ °C, unless otherwise noted

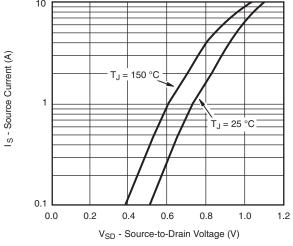


**Gate Charge** 

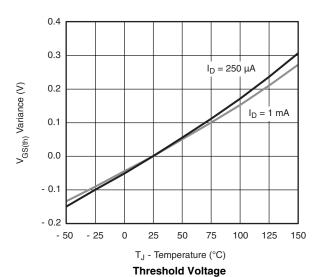
On-Resistance vs. Junction Temperature

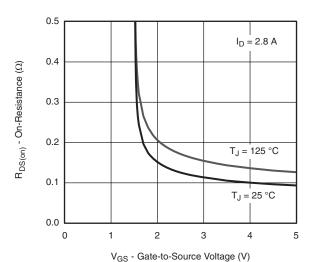
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## **TYPICAL CHARACTERISTICS** $T_A = 25$ °C, unless otherwise noted

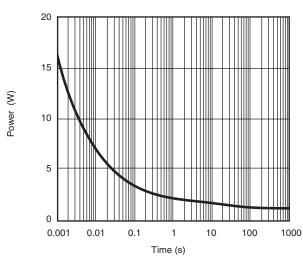


#### Soure-Drain Diode Forward Voltage

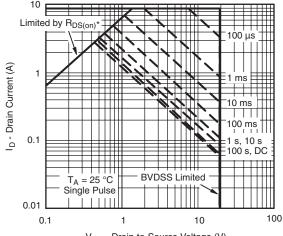




On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient



V<sub>DS</sub> - Drain-to-Source Voltage (V)

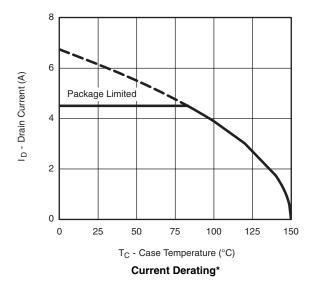
Safe Operating Area, Junction-to-Case

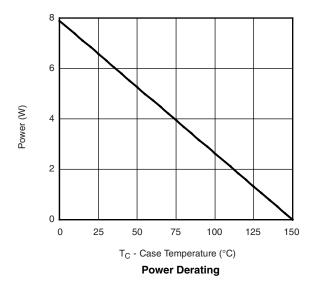
<sup>\*</sup>  $V_{GS}$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified





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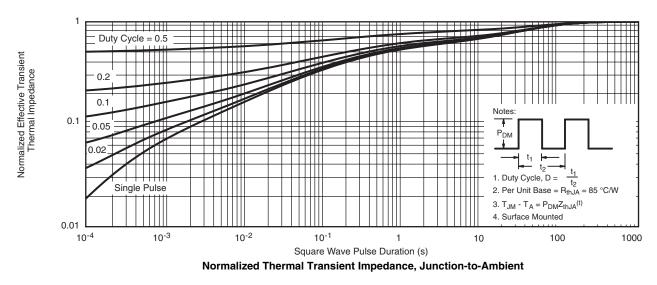


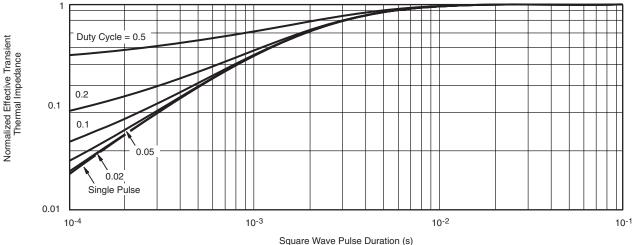


<sup>\*</sup> The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



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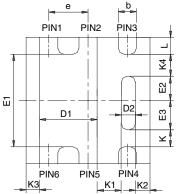
Normalized Thermal Transient Impedance, Junction-to-Case

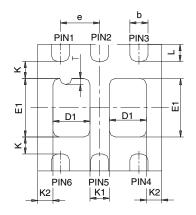
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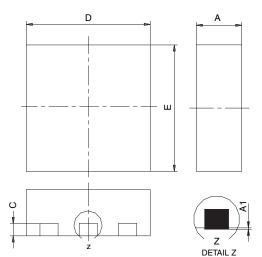
## PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
   Package outline exclusive of mold flash and metal burr
   Package outline inclusive of plating

	SINGLE PAD						DUAL PAD					
DIM	M	ILLIMETER	RS		INCHES		М	ILLIMETER	RS		INCHES	
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
<b>A</b> 1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D2	0.135	0.235	0.335	0.005	0.009	0.013						
Е	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E2	0.345	0.395	0.445	0.014	0.016	0.018						
E3	0.425	0.475	0.525	0.017	0.019	0.021						
е		0.65 BSC			0.026 BSC	;		0.65 BSC			0.026 BSC	
K		0.275 TYP			0.011 TYP	1	0.275 TYP			0.011 TYP		
K1		0.400 TYP			0.016 TYP		0.320 TYP			0.013 TYP		
K2		0.240 TYP		0.009 TYP		0.252 TYP			0.010 TYP			
К3		0.225 TYP		0.009 TYP								
K4		0.355 TYP		0.014 TYP								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
Т							0.05	0.10	0.15	0.002	0.004	0.006
ECNI: C O	I: C 0.7421 Pay C 06 Aug 0.7											

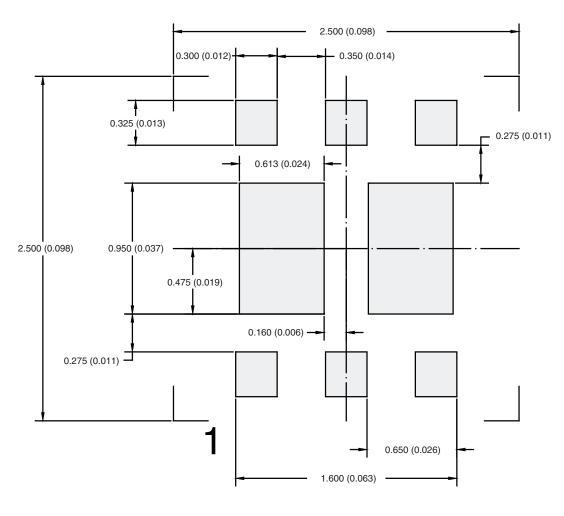
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Document Number: 73001 06-Aug-07

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### RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Dual



Dimensions in mm (inches)

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